

## P-Channel 150-V (D-S) MOSFET

### PRODUCT SUMMARY

$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)	$Q_g$ (Typ.)
- 150	0.635 at $V_{GS} = - 10$ V	- 1.1	7.7
	0.890 at $V_{GS} = - 4.5$ V	- 0.7	

### FEATURES

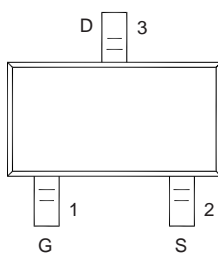
- TrenchFET Power MOSFET
- Small Size
- 100%  $R_g$  and UIS Tested


**RoHS**  
 COMPLIANT

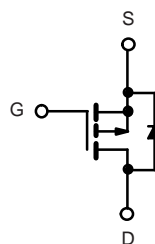
### APPLICATIONS

- Active Clamp Circuits in DC/DC Power Supplies

(SOT-23-3L)



Top View



P-Channel MOSFET

### ABSOLUTE MAXIMUM RATINGS $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted

Parameter	Symbol	LIMIT	
Drain-Source Voltage	$V_{DS}$	- 150	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current ( $T_J = 150\text{ }^{\circ}\text{C}$ ) <sup>a, b</sup>	$T_A = 25\text{ }^{\circ}\text{C}$	$I_D$	A
	$T_A = 70\text{ }^{\circ}\text{C}$		
Pulsed Drain Current	$I_{DM}$	- 4.0	
Continuous Source Current (Diode Conduction) <sup>a, b</sup>	$I_S$	- 1.1	
Single Pulse Avalanche Current	$L = 1.0\text{ mH}$	$I_{AS}$	1.0
Single Pulse Avalanche Energy		$E_{AS}$	1.01
Maximum Power Dissipation <sup>a, b</sup>	$T_A = 25\text{ }^{\circ}\text{C}$	$P_D$	0.75
	$T_A = 70\text{ }^{\circ}\text{C}$		0.48
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150	$^{\circ}\text{C}$

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	$R_{thJA}$	75	100	$^{\circ}\text{C/W}$
		120	166	
Maximum Junction-to-Foot (Drain)	$R_{thJF}$	40	50	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. Pulse width limited by maximum junction temperature.

**SPECIFICATIONS**  $T_J = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted

Parameter	Symbol	Test Conditions	Limits			Unit
			Min.	Typ.	Max.	
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$	-150			V
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$	-2.0		-4.0	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -120\text{ V}, V_{GS} = 0\text{ V}$			-1	$\mu\text{A}$
		$V_{DS} = -120\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^{\circ}\text{C}$			-10	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \leq -15\text{ V}, V_{GS} = 10\text{ V}$	-1.1			A
Drain-Source On-Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = -10\text{ V}, I_D = -0.5\text{ A}$		635	795	m $\Omega$
		$V_{GS} = -4.5\text{ V}, I_D = -0.5\text{ A}$		890	1150	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = -15\text{ V}, I_D = -0.5\text{ A}$		2.2		S
Diode Forward Voltage	$V_{SD}$	$I_S = -1.0\text{ A}, V_{GS} = 0\text{ V}$		-0.7	-1.2	V
Dynamic <sup>b</sup>						
Total Gate Charge	$Q_g$	$V_{DS} = -120\text{ V}, V_{GS} = 10\text{ V},$ $I_D \cong -0.5\text{ A}$		7.7	12	nC
Gate-Source Charge	$Q_{gs}$			1.5		
Gate-Drain Charge	$Q_{gd}$			2.5		
Gate Resistance	$R_g$	$f = 1.0\text{ MHz}$		9		$\Omega$
Input Capacitance	$C_{iss}$	$V_{DS} = -25\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		340	510	pF
Output Capacitance	$C_{oss}$			30		
Reverse Transfer Capacitance	$C_{rss}$			16		
Switching <sup>c</sup>						
Turn-On Time	$t_{d(on)}$	$V_{DD} = -120\text{ V}, R_L = 75\text{ }\Omega$ $I_D \cong -1.0\text{ A}, V_{GEN} = -10\text{ V}$ $R_g = 6\text{ }\Omega$		7	11	ns
	$t_r$			11	17	
Turn-Off Time	$t_{d(off)}$			16	25	
	$t_f$			11	17	
Body Diode Reverse Recovery Charge	$Q_{rr}$	$I_F = 0.5\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$		90	135	nC

Notes:

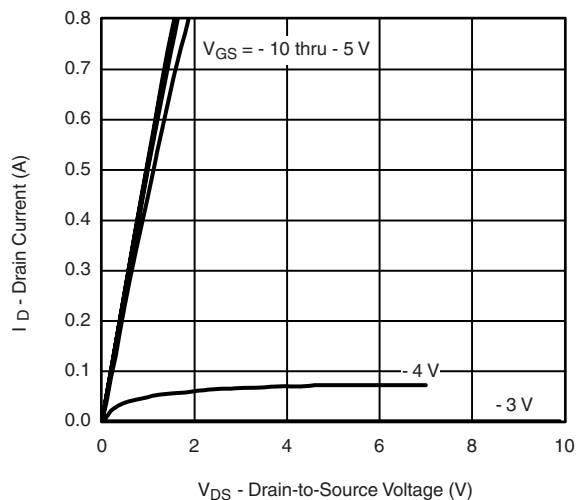
 a. Pulse test:  $PW \leq 300\text{ }\mu\text{s}$  duty cycle  $\leq 2\%$ .

b. For DESIGN AID ONLY, not subject to production testing.

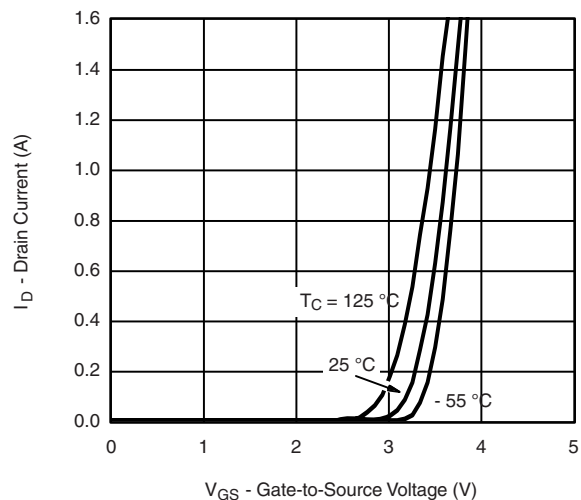
c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

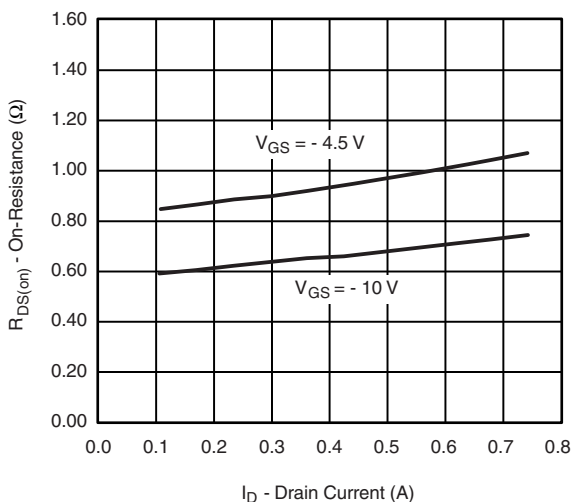
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



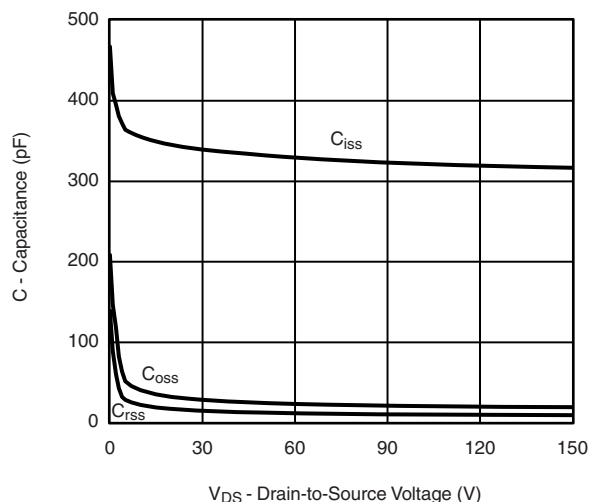
**Output Characteristics**



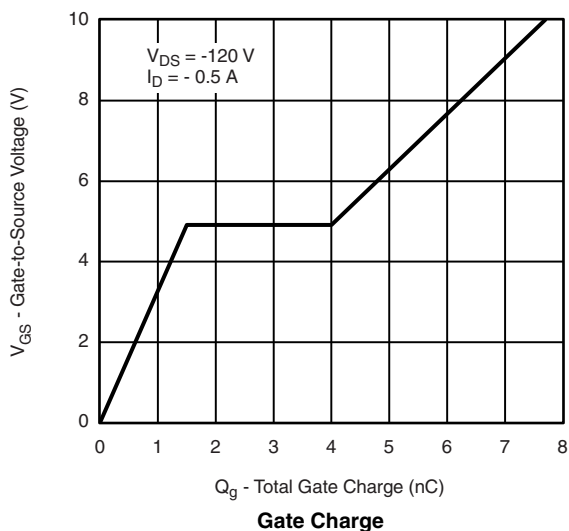
**Transfer Characteristics**



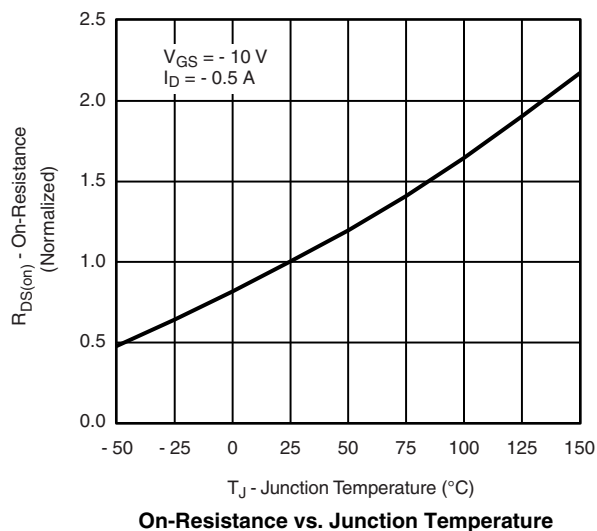
**On-Resistance vs. Drain Current**



**Capacitance**

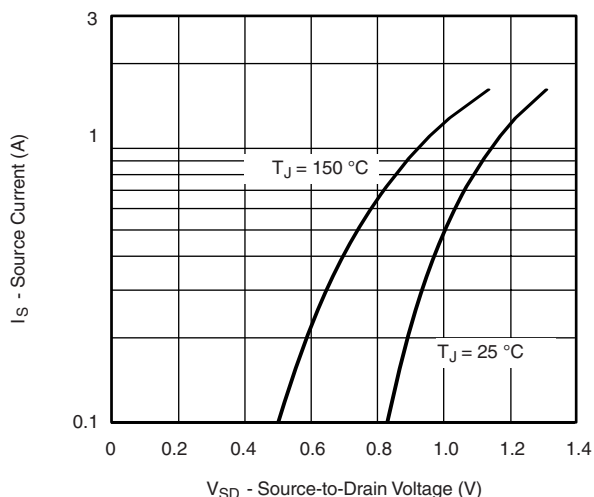


**Gate Charge**

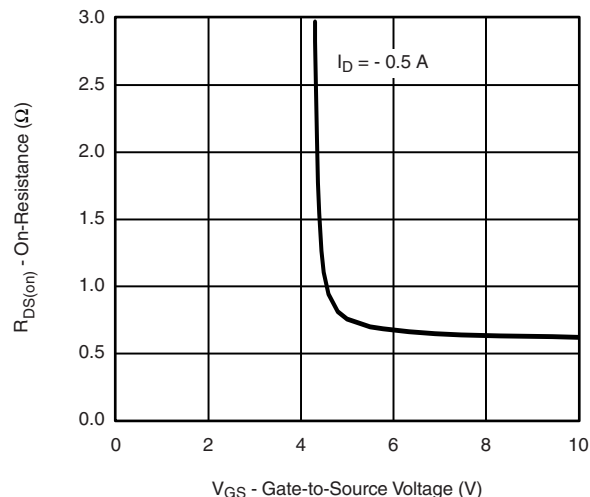


**On-Resistance vs. Junction Temperature**

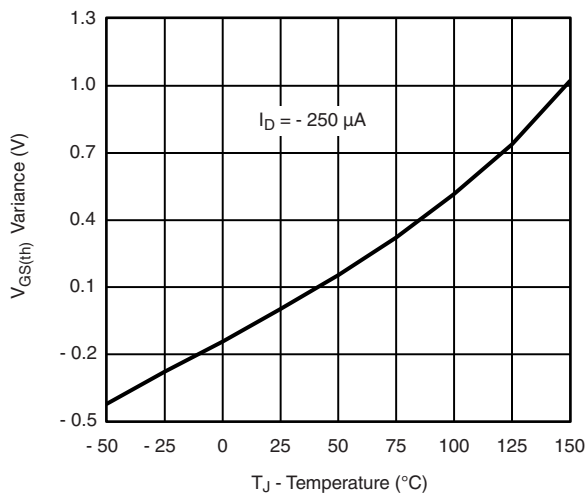
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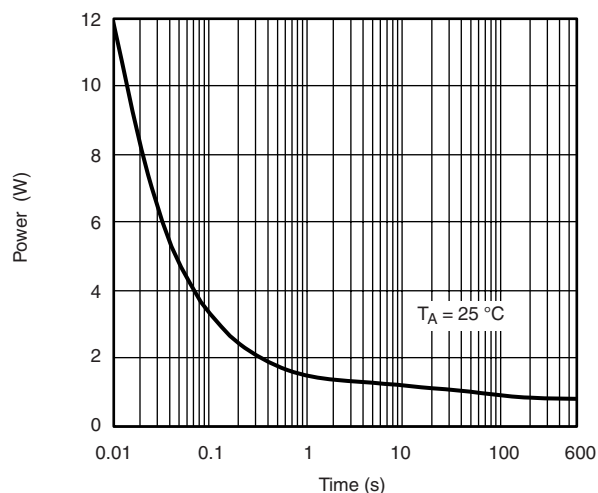
Source-Drain Diode Forward Voltage



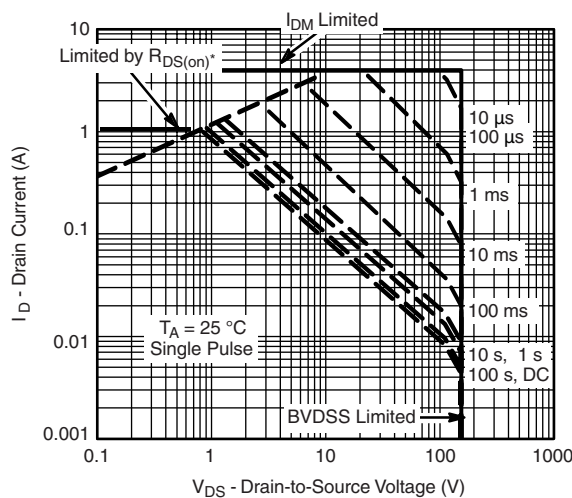
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



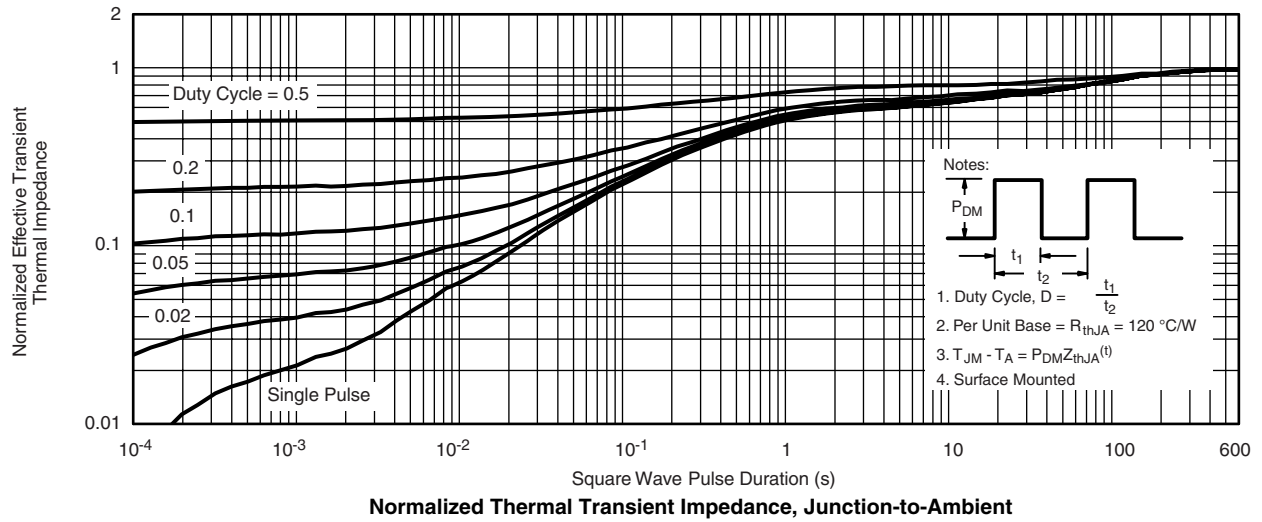
Single Pulse Power



\*  $V_{GS} >$  minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

Safe Operating Area

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



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